MSKSEMI 美森科
SEMICONDUCTOR

ESD TVS TSS MOV GDT PLED

GBL4005-MS THRU GBL410-MS

Product specification

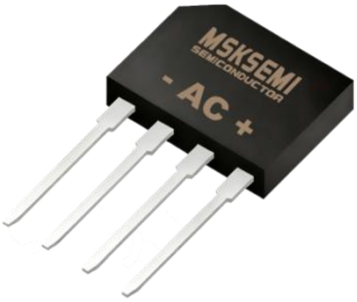
REVERSE VOLTAGE - 50 to 1000 Volts
FORWARD CURRENT - 4.0 Amperes

FEATURES

- The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- Idea for printed circuit board
- Glass passivated Junction chip
- Low reverse leakage
- High forward surge current capability
- High temperature soldering guaranteed 260 C/10 seconds at terminals

REFERENCE NEWS

GBL



MECHANICAL DATA

- **Case** : Molded plastic body
- **Terminals** : Solder plated, solderable per MIL-STD-750,Method 2026
- **Polarity** : Polarity symbol marking on body
- **Mounting Position** : Any
- **Weight**: 0.076 ounces , 2.15 grams

Marking

GBL4005-MS	GBL401-MS	GBL402-MS	GBL404-MS
 MSKSEMI GBL4005 + AC -	 MSKSEMI GBL401 + AC -	 MSKSEMI GBL402 + AC -	 MSKSEMI GBL404 + AC -
GBL406-MS	**GBL408-MS**	**GBL410-MS**	
 MSKSEMI GBL406 + AC -	 MSKSEMI GBL408 + AC -	 MSKSEMI GBL410 + AC -	

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25℃ ambient temperature unless otherwise specified. Single phase half-wave 60Hz,resistive or inductive load, for capacitive load current derate by 20%.

CHARACTERISTICS	SYMBOL	GBL4005 -MS	GBL401 -MS	GBL402 -MS	GBL404 -MS	GBL406 -MS	GBL408 -MS	GBL410 -MS	UNIT
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Bridge Input Voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Output Current @ T_A=50℃ (Note1)	$I_{(AV)}$	4.0							A
Peak Forward Surage Current 8.3ms Single Half Sine-Wave Super Imposed on Rated Load	I_{FSM}	125							A
Maximum Forward Voltage Drop Per Bridge Element at 4.0A Peak	V_F	1.1							V
Maximum Reverse Current at Rated DC Blocking Voltage	I_R	10.0							uA
Maximum Reverse Current at Rated DC Blocking Voltage @ T_A =150℃	I_R	1.0							mA
Operating Temperature Range	T_J	-55 to +150							℃
Storage Temperature Range	T_{STG}	-55 to +150							℃

Note:1.Mounting conditions,0.5″lead length maximum.

Ratings And Characteristic Curves

FIG.1-FORWARD DERATING CURRENT

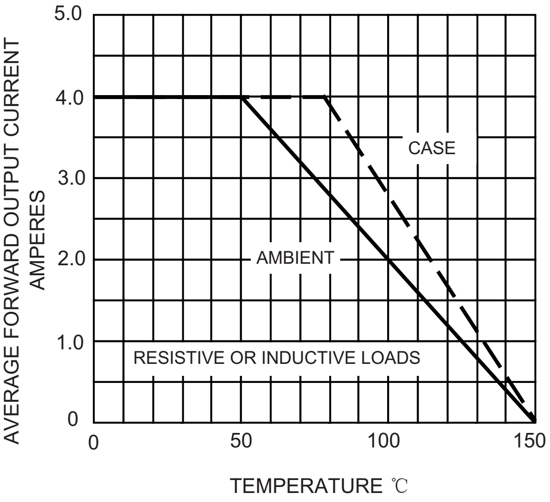


FIG.2-MAXIMUM NON-REPETITIVE SURGE CURRENT

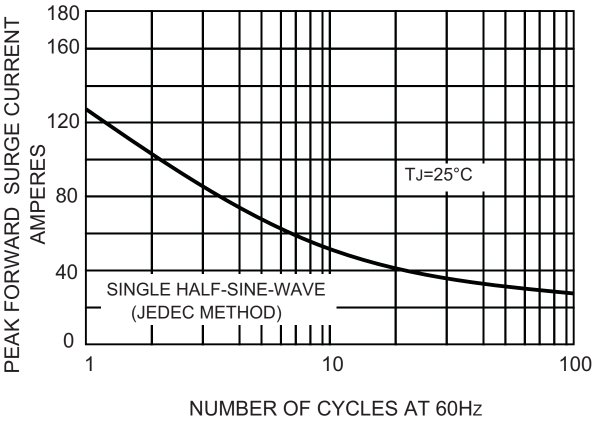


FIG.3-TYPICAL FORWARD CHARACTERISTICS

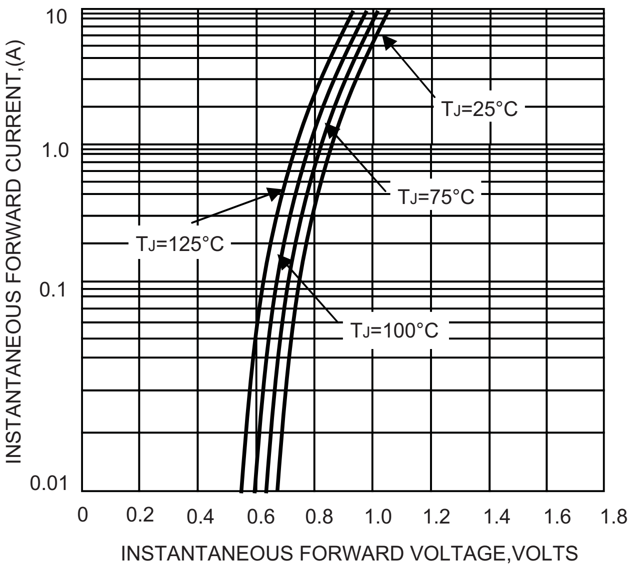
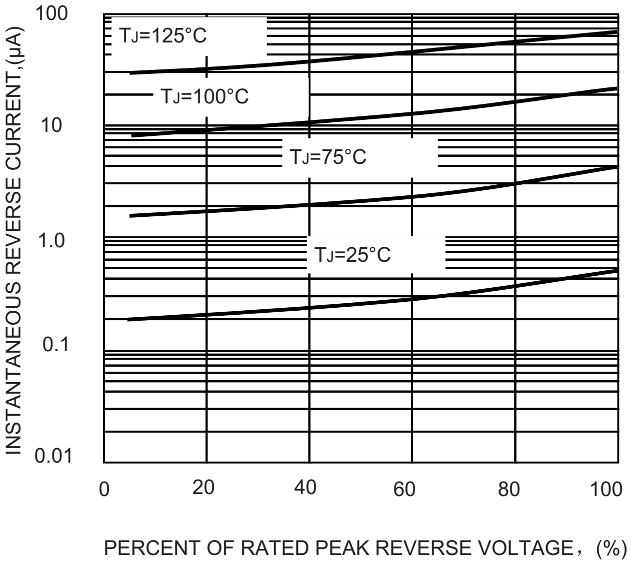
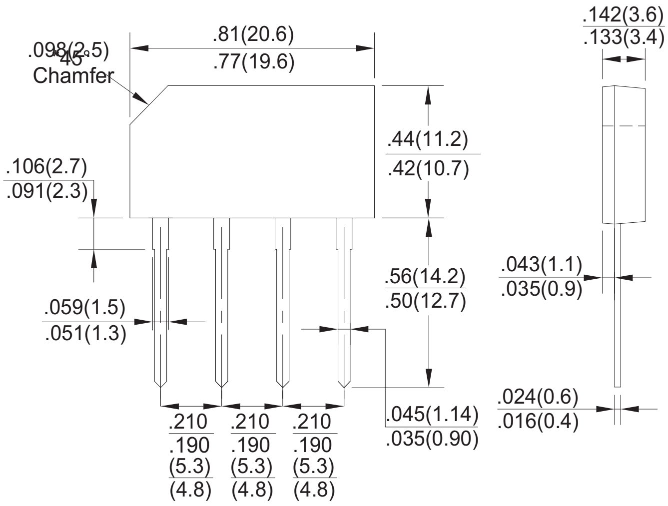


FIG.4-TYPICAL REVERSE CHARACTERISTICS



PACKAGE MECHANICAL DATA

GBL



Dimensions in inches and (milimeters)

REELSPECIFICATION

P/N	PKG	QTY
GBL4005-MS THRU GBL410-MS	GBL	500

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